

1. General description

Silicon Carbide Schottky diode in a SOD59A (TO-220AC) plastic package, designed for high frequency switched-mode power supplies.

2. Features and benefits

- Highly stable switching performance
- High forward surge capability IFSM
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

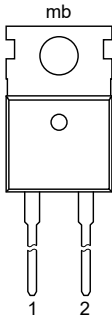
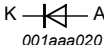
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	650	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 76 °C; square-wave pulse; Fig. 1 ; Fig. 2 ; Fig. 3		-	-	20	A
T _j	junction temperature			-	-	175	°C
Static characteristics							
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; Fig. 5		-	1.5	1.7	V
		I _F = 20 A; T _j = 150 °C; Fig. 5		-	1.8	2.1	V
Dynamic characteristics							
Q _r	recovered charge	I _F = 20 A; dI _F /dt = 500 A/μs; V _R = 400 V; T _j = 25 °C; Fig. 6		-	28	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		 001aaa020
2	A	anode		
mb	mb	mounting base; connected to cathode		
			TO-220AC (SOD59A)	

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NXPSC20650	TO-220AC	Plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59A

7. Marking

Table 4. Marking codes

Type number	Marking code
NXPSC20650	NXPSC20650

8. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	650	V
V _{RWM}	crest working reverse voltage		-	650	V
V _R	reverse voltage	DC	-	650	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 76 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	20	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 76 °C; square-wave pulse	-	40	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; SIN	-	100	A
		t _p = 10 μs; T _{j(init)} = 25 °C; SIN	-	900	A
T _{stg}	storage temperature		-55	175	°C
T _j	junction temperature		-	175	°C

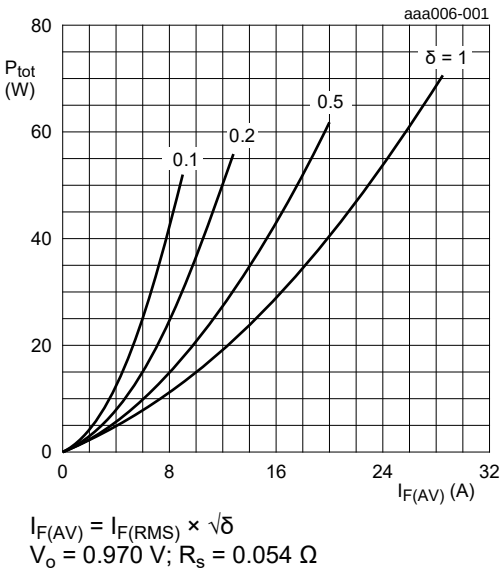


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

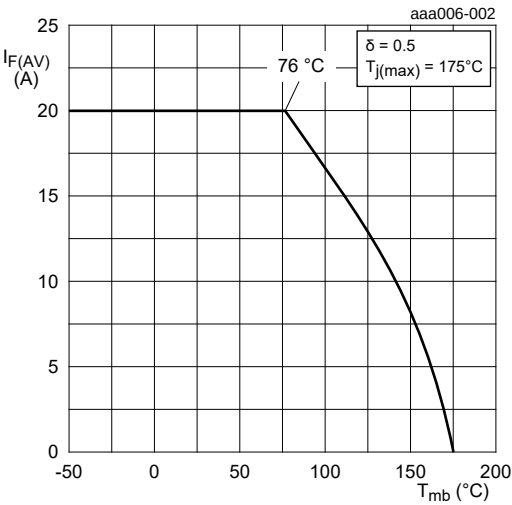


Fig. 2. Forward current as a function of mounting base temperature; maximum values

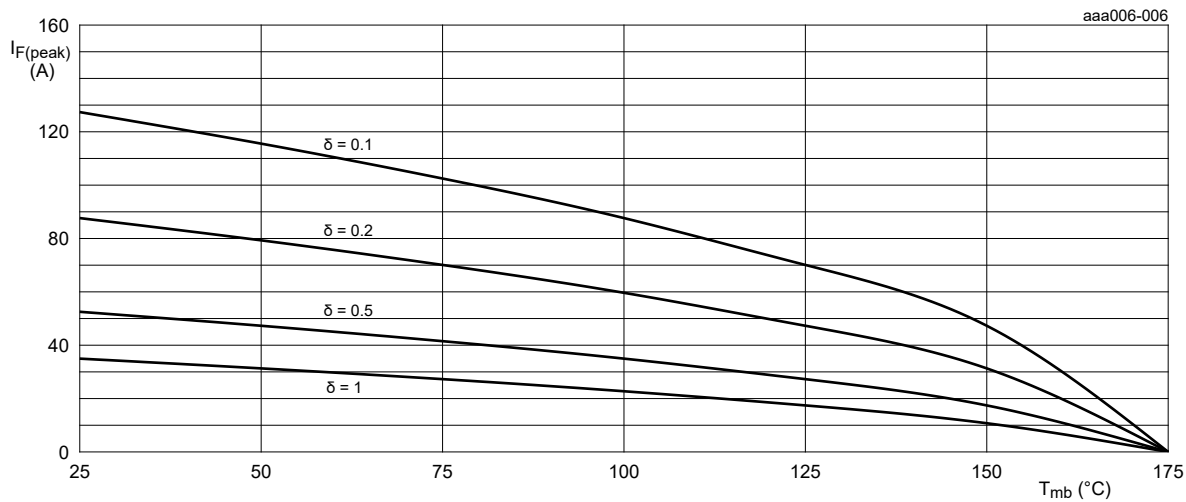


Fig. 3. Current derating as a function of mounting base temperature

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 4		-	-	1.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

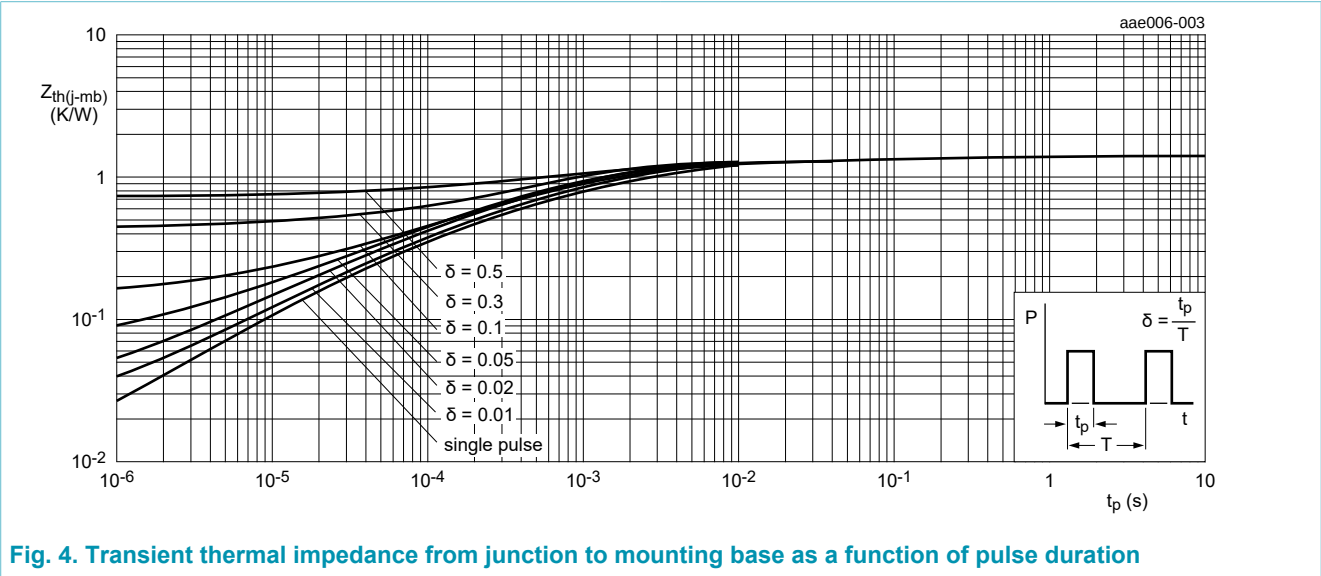
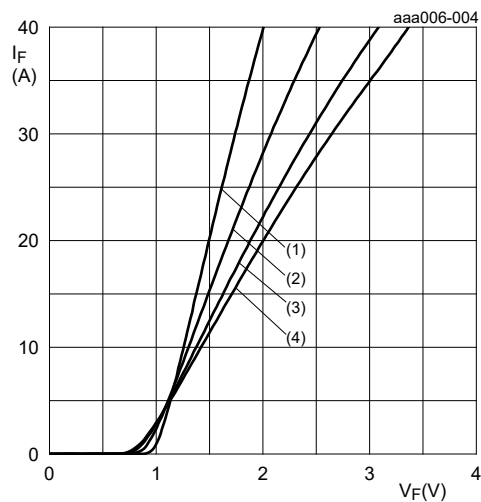


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; Fig. 5		-	1.5	1.7	V
		I _F = 20 A; T _j = 150 °C; Fig. 5		-	1.8	2.1	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C		-	-	500	μA
		V _R = 650 V; T _j = 150 °C		-	-	1600	μA
Dynamic characteristics							
Q _r	recovered charge	I _F = 20 A; dI _F /dt = 500 A/μs; V _R = 400 V; T _j = 25 °C; Fig. 6		-	28	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C		-	600	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C		-	64	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C		-	50	-	pF



V_o = 0.970 V; R_s = 0.054 Ω
(1) T_J = 25 °C; typical values
(2) T_J = 100 °C; typical values
(3) T_J = 150 °C; typical values
(4) T_J = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

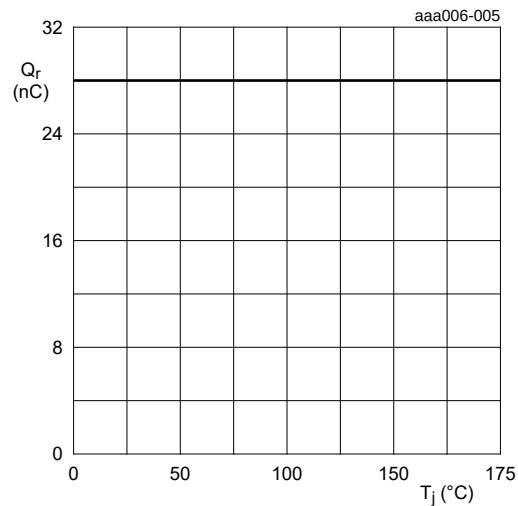


Fig. 6. Recovered charge as a function of junction temperature

11. Package outline

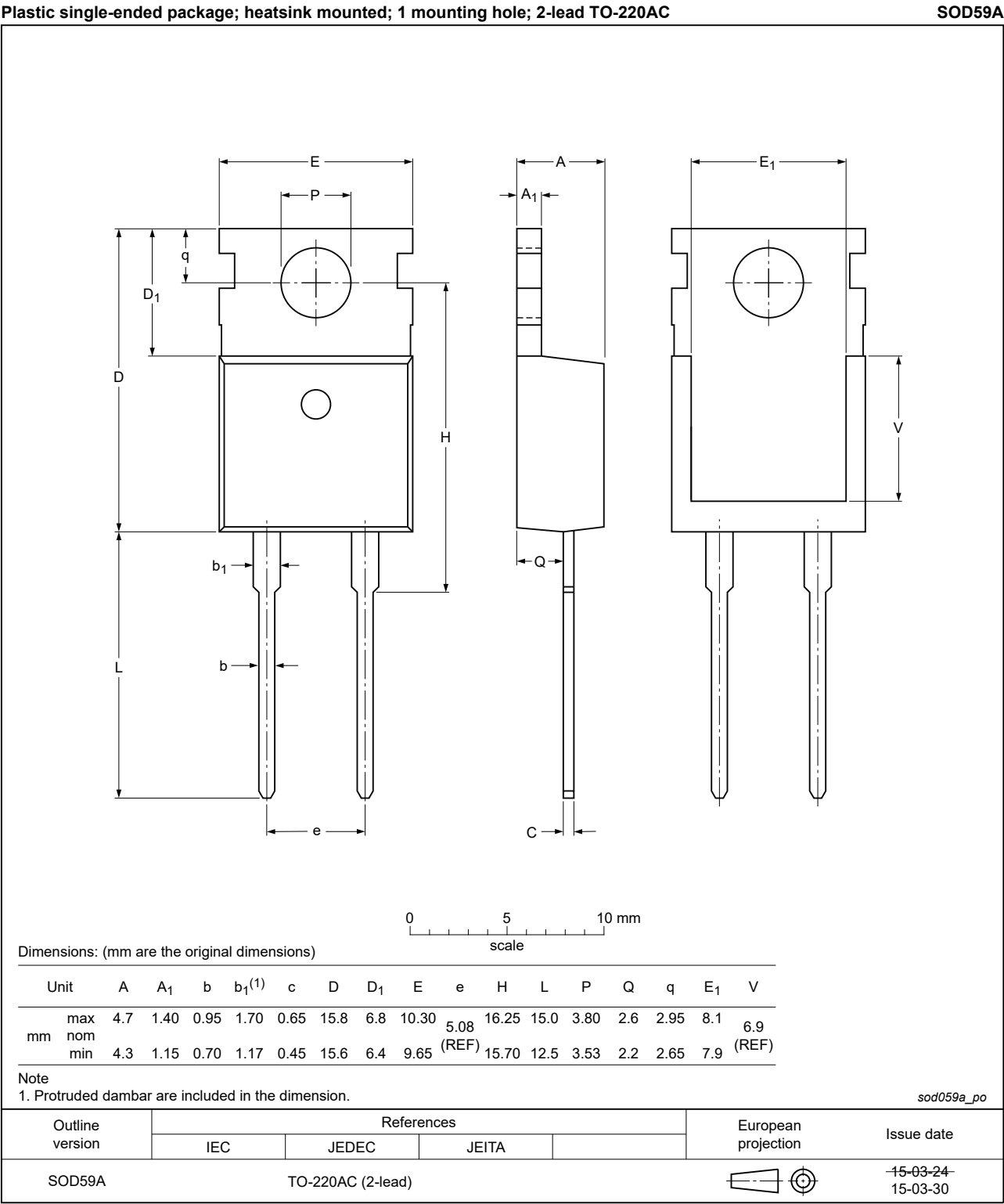


Fig. 7. Package outline TO-220AC (SOD59A)

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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